NSN 5961-01-541-9339

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-541-9339 **Inclosure Material:** Plastic **Overall Length:** 0.229 inches **Mounting Method:** Terminal **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 13.3 breakdown voltage, dc **Current Rating Per Characteristic:** 34.00 amperes forward current, total rms **Product Name:** Low capacitance tvs array **Terminal Type And Quantity:** 8 pin Shelf Life: N/a **Unit Of Measure: Demilitarization:**

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